

# Operation of MMCs with Dynamic Temperature-Dependent Current Limits

Manchester Electrical Energy and Power Systems  
Workshop

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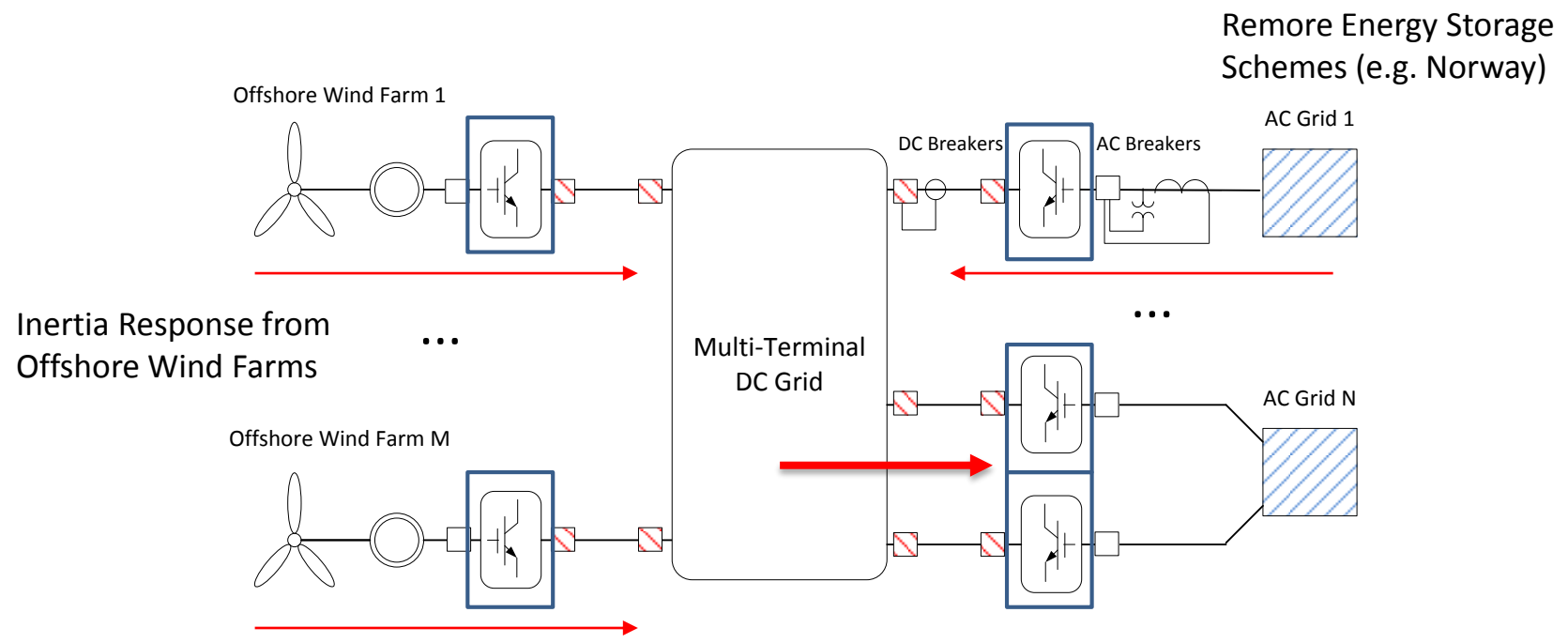


# Outline

- Modular Multilevel Converter:
  - Structure and Control
  - Limits and Constraints
  - Electro-Thermal Model
  - Dynamic Temperature-Dependent Current Limits
- Case Study
- Results
- Conclusions & Future Work



# Big Picture...

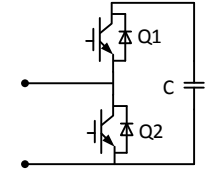
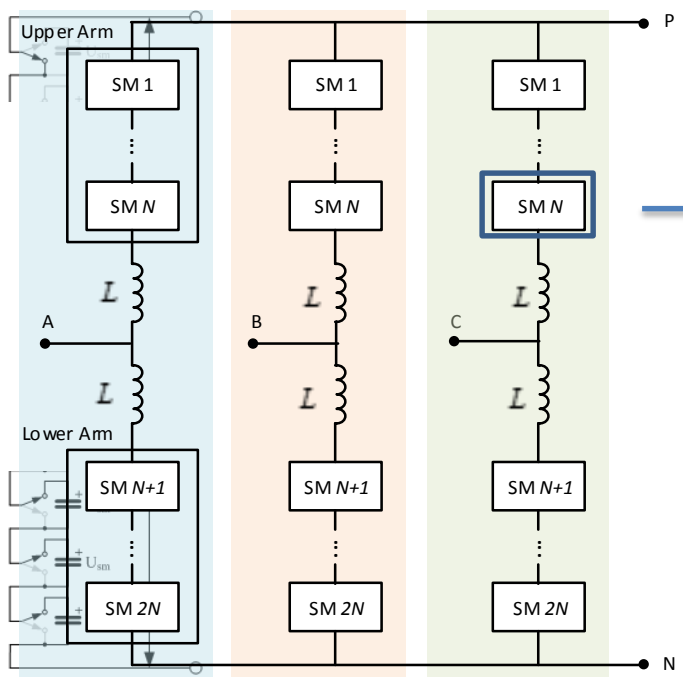
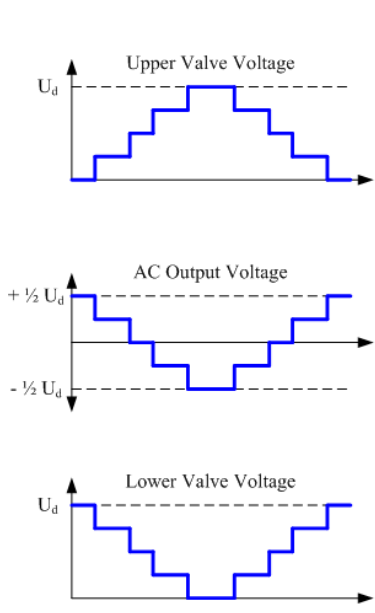


Under power unbalance conditions, additional transmission capability might be necessary.

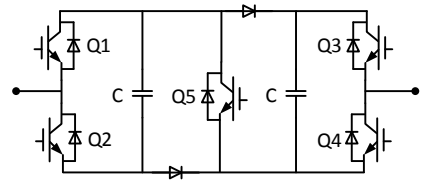


# Modular Multilevel Converter

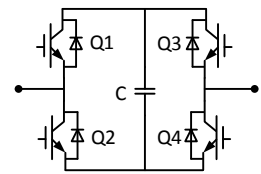
- Structure and Operation



Half-Bridge



Clamp Double

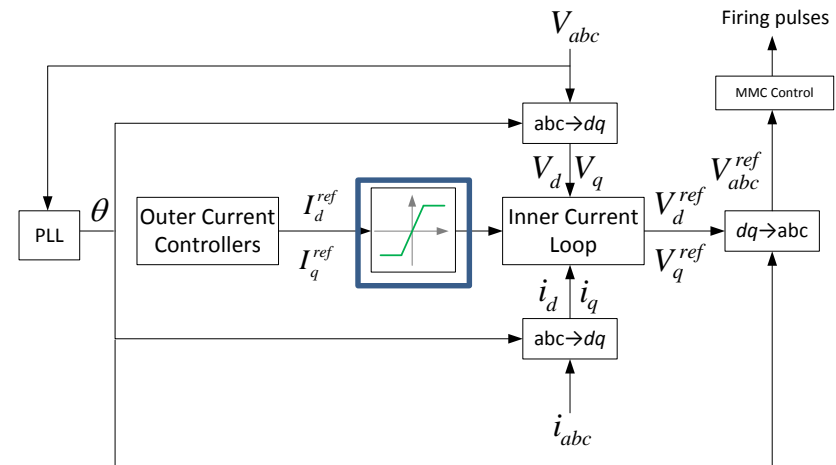
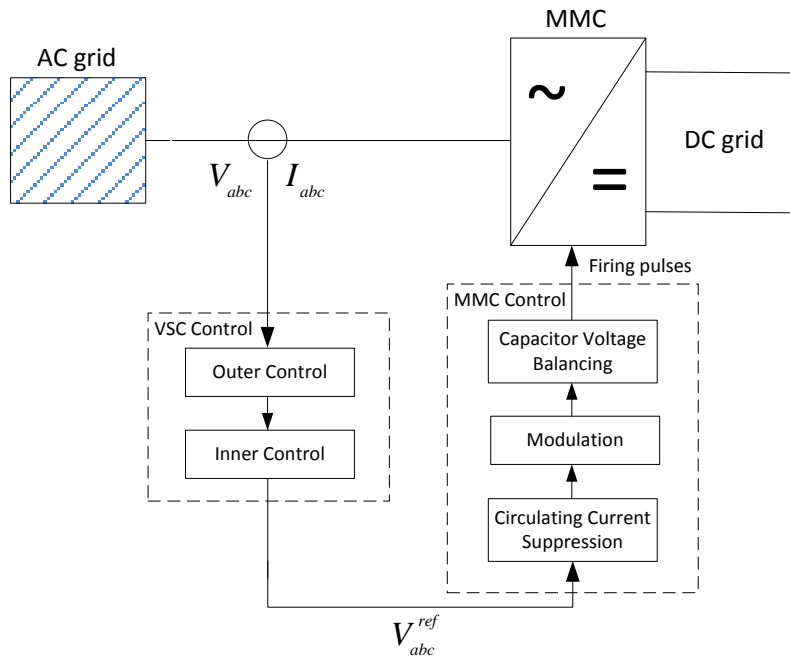


Full Bridge



# Modular Multilevel Converter

- Control ( $dq0$  reference frame)



- Fixed limits set the maximum power contribution from the converter
- Must ensure that thermal limits are not exceeded



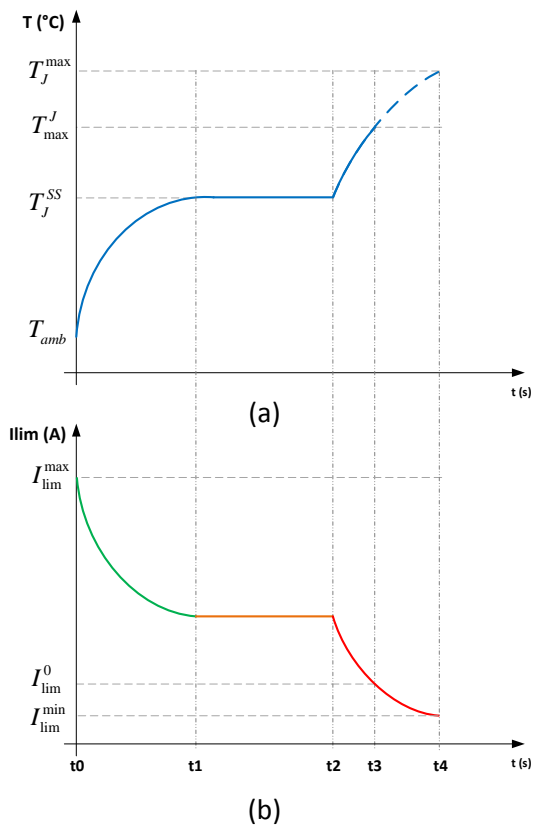
# Modular Multilevel Converter

- Limits and Constraints
  - Besides electrical, semiconductors have strict thermal limits that must be respected;
  - A more robust control system must ensure that the necessary constraints are respected, **without limiting the transmission capacity**;
  - In this work a combined approach is proposed, where the current limits are sensitive to the temperature dynamics in the semiconductors.

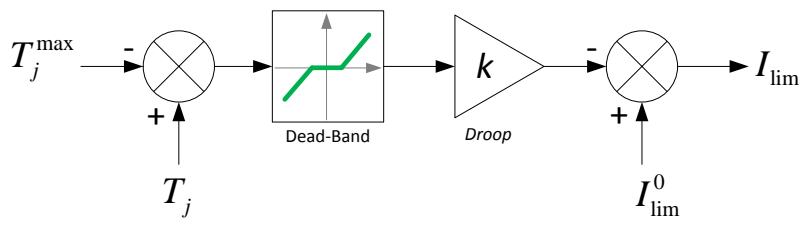


# MMC Electro-Thermal Model

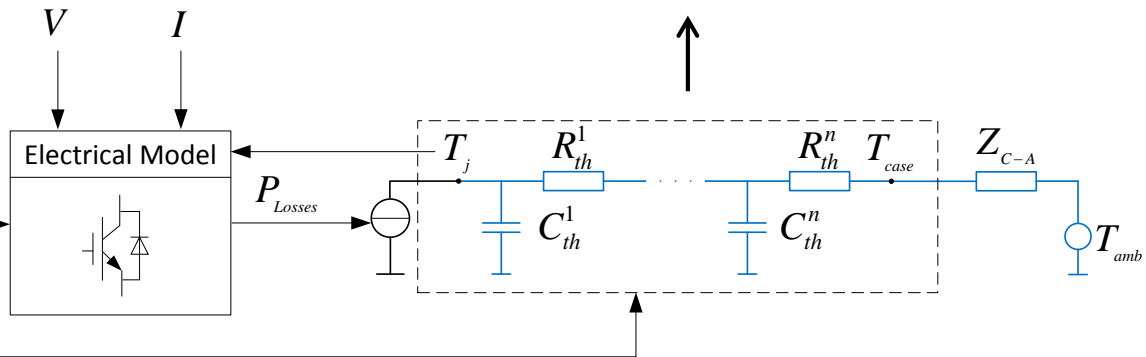
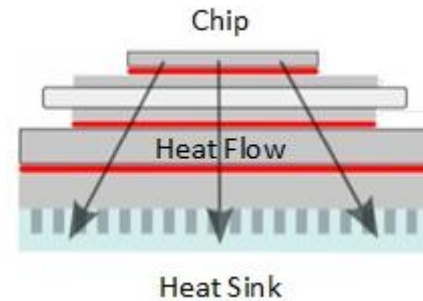
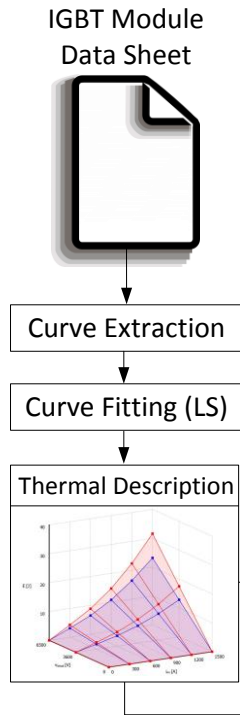
## Dynamic Temperature-Dependent Current Limits



$$I_{lim}(T_J) = I_{lim}^0 + k(T_{max}^J - T_J)$$



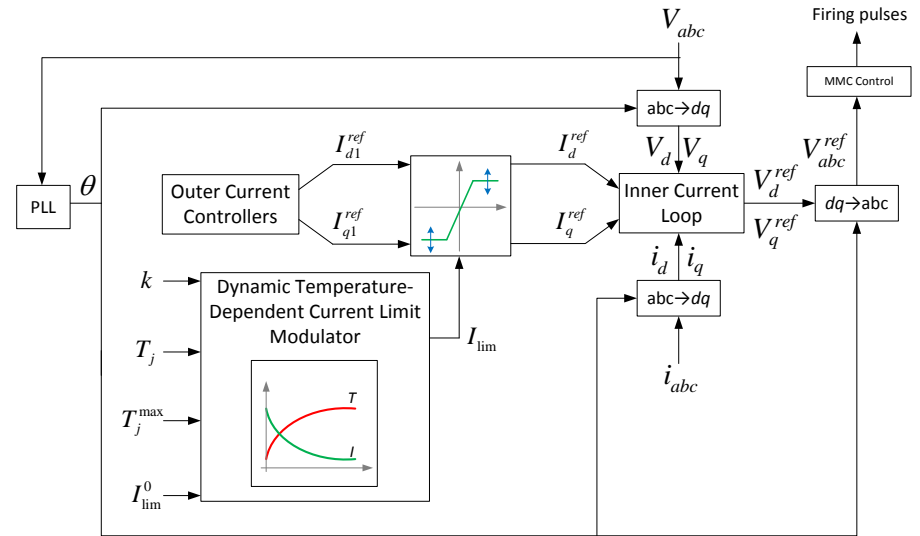
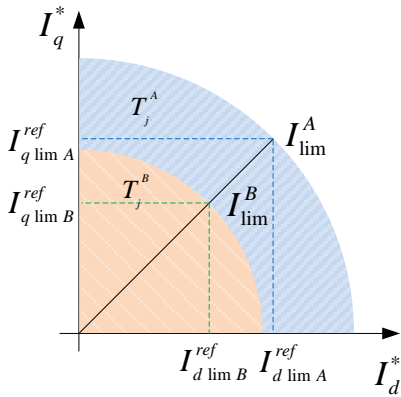
# MMC Electro-Thermal Model





# MMC Electro-Thermal Model

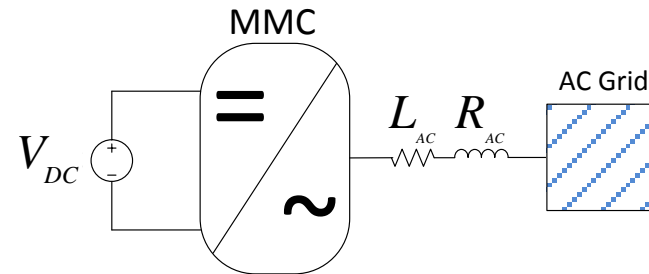
## Dynamic Temperature-Dependent Current Limits



# Case Study

## System Data

AC System Data	
$V_{AC}$ (kV)	15
$f$ (Hz)	50
MMC and DC System Data	
$V_{DC}$ (kV)	30
#SM	10
$V_{cap}$ (V)	3000
$f_c$ (Hz)	1000
IGBT Data	
Model	ABB 5SNA 0650J450300
$V_{CE}$ (V)	4500
$I_{CE}$ (A)	650

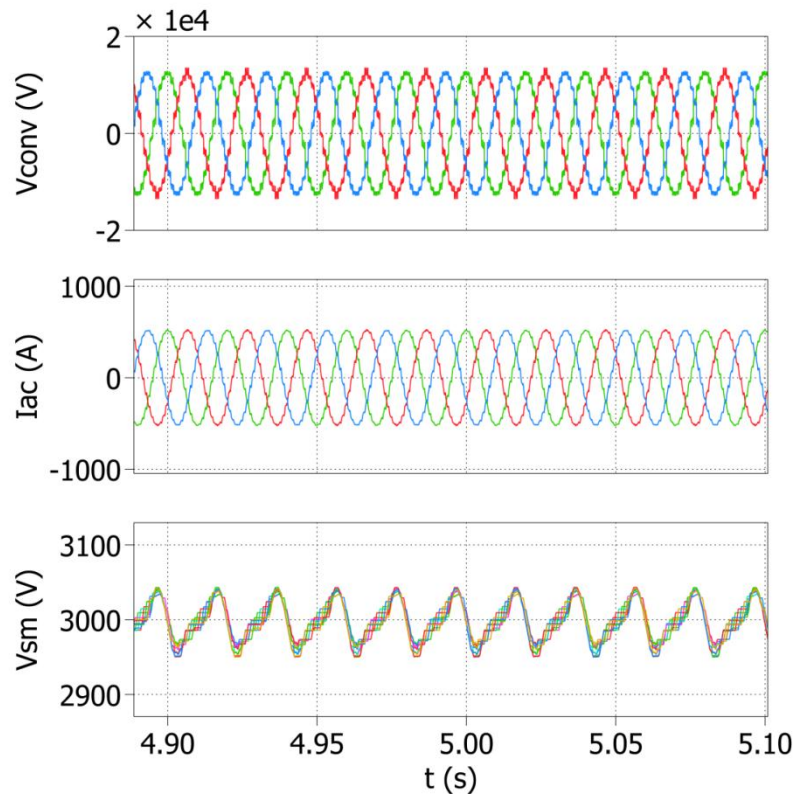


$$\left\{ \begin{array}{l} T_{\max}^J = 85 \text{ }^\circ\text{C} \\ I_{\text{lim}}^0 = 650 \text{ A} \\ k = 16.25 \text{ A/}^\circ\text{C} \end{array} \right.$$



# Results

## I. Operational Quantities



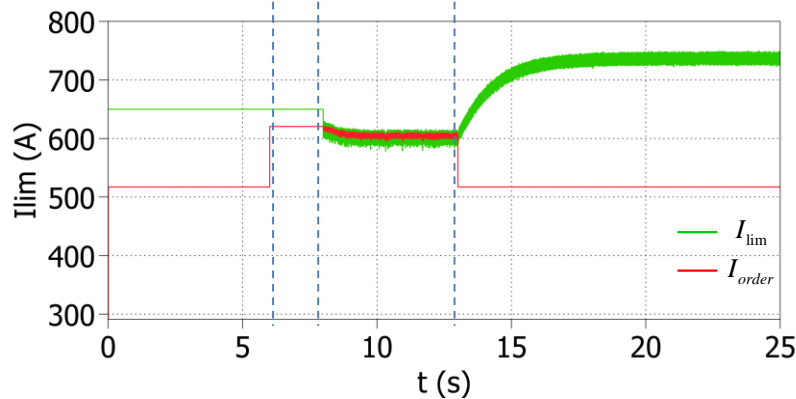
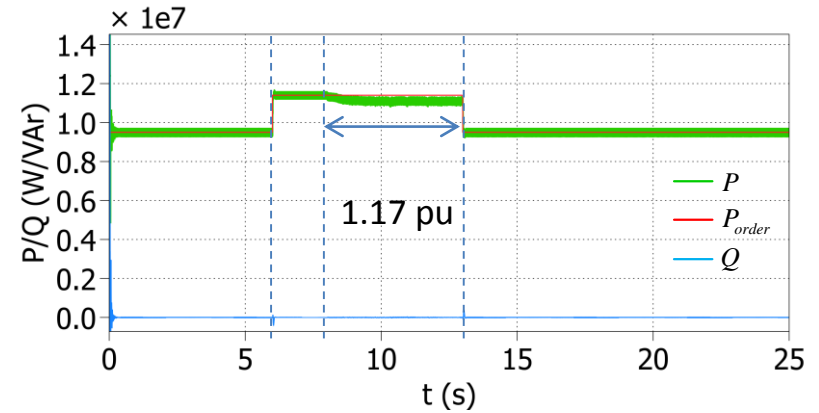
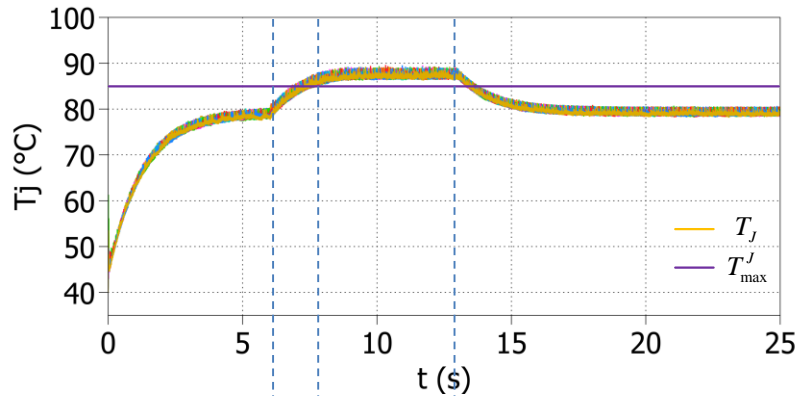
System Dynamics:

- $P^*$ : 9.5  $\rightarrow$  11.4 MW (1  $\rightarrow$  1.2 pu) @ 6s
- CLM activated @ 8s
- $P^*$ : 11.4  $\rightarrow$  9.5 MW (1.2  $\rightarrow$  1 pu) @ 13s



# Results

## II. Dynamic Temperature-Dependent Current Limits



Extension of power transmission capability  
+  
Respect of electrical and thermal limits  
=  
Seamless power support to an unbalanced grid



# Conclusions & Future Work

- I. Proposed strategy to control the current limits with sensitivity to semiconductors junction temperature;
- II. Transmission capacity can be dynamically controlled, while respecting electrical and thermal constraints, enabling the support to grids with power imbalance;
- III. Operation under fault conditions (not shown) was verified and confirms the validity of the proposed control;
- IV. Experimental validation is on its way.



# Thank you for your attention!

